AMENDMENTS TO THE CLAIMS

This listing of claims will replace all prior versions, and listings, of claims in the application:

<u>Listing of Claims:</u>

(Currently Amended) An apparatus for wet processing the device side of 1. individual wafers, comprising:

an acoustic energy generator;

a wafer bracket for positioning a wafer having a clevice side and a non-device side over the acoustic generator, wherein the device side of the wafer is distal to the acoustic generator and the non-device side of the wafer is proximate to the acoustic generator;

means for holding a wafer having a non-device side and a device side over means for providing acoustic energy such that said means for providing acoustic energy is adjacent to said wafer non device side;

a first liquid dispenser means for flowing a first liquid between said means for applying said acoustic energy generator and said wafer; and

wherein the first liquid is in extensive contact with both the acoustic generator and the wafer, providing the predominant means of transferring acoustic energy from the acoustic generator to the non-device side of the wafer;

a second liquid dispenser means for flowing a processing liquid onto said device side of the wafer; and

wherein the acoustic energy irradiating the non-device side of the wafer is transferred to the device side of the wafer having a frequency and intensity at the device side of the wafer to provide a substantive improvement in the cleaning

Application No.: 09/891,849 Filing Date: June 25, 2001

-2/23-

performance of the processing liquid on the device side of the wafer, while also minimizing the associated risk of damage to the devices on the wafer due to the sonic energy acting on the device side of the wafer.

- 2. (Previously Presented) The apparatus for wet processing individual wafers of claim 1, wherein the acoustic energy strikes the wafer non-device side perpendicular.
- 3. (Currently Amended) The apparatus for wet processing individual wafers of claim 1, wherein the acoustic energy generator further comprises comprises:

means for mounting one or more acoustic wave transducers mounted on the acoustic generator and positioned; and

— means for positioning-the one or more acoustic wave transducers to be parallel to and facing the non-device side of the wafer.

- 4. (Canceled)
- 5. (Currently Amended) The apparatus for wet processing individual wafers of claim 1, wherein means for providing the acoustic energy generator comprises to a non-device side of the wafer is carried out by a platter having a frontside and a backside; and wherein the one or more acoustic wave transducers are mounted on the platter backside.
- 6. (Original) The apparatus for wet processing individual wafers of claim 1, further comprising:

a device for rotating the wafer.

Application No.: 09/891,849 Filing Date: June 25, 2001

- 3/23-

AMAT Ref. No.: 004711USAPY1/W-C/W-C/ BSTZ Ref. No.: 004887.P454X 7. (Original) The apparatus for wet processing individual wafers of claim 1, further comprising:

a device for linearly transporting the wafer.

- 8. (Currently Amended) The apparatus for wet processing individual wafers of claim 1, wherein means for flowing a liquid onto the device side of a wafer the second liquid dispenser is a nozzle positioned to direct a liquid flow onto the device side of the wafer.
- 9. (Currently Amended) The apparatus for wet processing individual wafers of claim 3, wherein the one or more acoustic wave transducers are comprise a piezoelectric material.
- (Original) The apparatus for wet processing individual wafers of claim 5, 10. wherein the platter is positioned parallel to the wafer surface, with the platter front side facing the wafer non-device side.
- (Original) The apparatus for wet processing individual wafers of claim 10, wherein the platter diameter is at least 95% the diameter of the wafer.
- 12. (Original) The apparatus for wet processing individual wafers of claim 11, wherein the one or more acoustic wave transducers are mounted on the platter backside to cover 50-100% of the platter backside area.
- (Original) The apparatus for wet processing individual wafers of claim 3, 13. wherein the one or more acoustic wave transducers cover the radius of a wafer.

Application No.: 09/891,849

Filing Date: June 25, 2001

AMAT Ref. No.: 004711USAPY1/W-C/W-C/

- 14. (Original) The apparatus for wet processing individual wafers of claim 3, wherein the one or more acoustic wave transducers cover the diameter of a wafer.
- 15. (Original) The apparatus for wet processing individual wafers of claim 3, wherein the one or more acoustic wave transducers provide acoustic energy to cover 50-100% of the non-device side of the wafer.
- 16. (Currently Amended) The apparatus for wet processing individual wafers of claim 1, wherein the acoustic energy generator comprises means for providing the one or more acoustic wave transducers to the non-device side of the wafer is constructed such as to have having a resonance frequency of 5.4 MHz ± 30% for 300 mm wafers.
- 17. (Canceled)
- 18. (Currently Amended) The apparatus for wet processing individual wafers of claim 1, wherein the acoustic energy generator comprises means for providing the one or more acoustic wave transducers to a non-device-side of the wafer is constructed-such as to have having a resonance frequency less than 1.5 MHz.
- 19. (Currently Amended) The apparatus for wet processing individual wafers of claim 1, wherein the provided generated acoustic energy is pulsed.

20-21. (Canceled)

22. (Original) The apparatus for wet processing individual wafers of claim 5, further comprising a through hole in the platter for flowing a liquid.

Application No.: 09/891,849 Filing Date: June 25, 2001

- 5/23-

- 23. (Original) The apparatus for wet processing individual wafers of claim 22, further comprising a fluid feed tube attached to the through hole at the platter backside.
- 24. (Original) The apparatus for wet processing individual wafers of claim 5, wherein a coating is applied to the platter frontside.
- 25. (Original) The apparatus for wet processing individual wafers of claim 24, wherein the coating is a fluoropolymer.

26-44. (Canceled)

- 45. (Currently Amended) An apparatus for wet processing a device side of individual wafers, comprising:
 - a platter having a frontside and a backside, comprising:

 a coating on the platter frontside,
- -----a greater diameter than the wafer to be processed,
- a plurality of megasonic piezoelectric transducers on the backside of attached to the backside of the platter, such that the transducers cover greater than 80% of the platter area;
- a wafer bracket to position a wafer having a device side and a non-device side over said platter such that said non-device side of the wafer is positioned substantially parallel to and centered over the platter front side so that a gap is formed between said wafer non-device side and said platter frontside;
- a liquid feed port for flowing a liquid in said gap between said wafer nondevice side and said platter frontside; and

Application No.: 09/891,849 Filing Date: June 25, 2001

- 6/23-

wherein said liquid fills said gap extensively contacting both the frontside of the platter and the non-device side of the wafer;

a nozzle capable of for directing a processing liquid flow toward onto said device side of the wafer to be processed, and

wherein said transducers apply megasonic energy to said platter, which transfers the megasonic energy to said liquid in said gap, which transfers to said non-device side of the wafer, which transfers to the device side of the wafer, and then, transfers the megasonic energy to the processing fluid on the device side of the wafer.

46. (Previously Presented) The apparatus for wet processing individual wafers of claim 45, wherein the plurality of transducer areas provide between 90-100% coverage of the wafer non-device side.

47-51. (Canceled)

52. (Previously Presented) The apparatus of claim 45 wherein said wafer bracket is capable of rotation up to 6000 rpm.

53-207. (Canceled)

(Previously Presented) An apparatus for wet processing a frontside of an individual wafer comprising:

a platter having a frontside and backside wherein said platter includes a plurality of megasonics transducers formed on said platter backside;

Application No.: 09/891,849

Filing Date: June 25, 2001

-7/23-

a wafer holder to position a wafer having a frontside and backside above said platter wherein said wafer backside is separated by a gap from said platter frontside;

an opening in said platter to flow a fluid in said gap between said wafer backside and said platter frontside; and

a nozzle positioned over said wafer frontside for directing a cleaning fluid onto said frontside of said wafer.

- 209. (Previously Presented) The apparatus of claim 208 wherein said hole is positioned substantially in the center of said platter.
- 210. (Previously Presented) The apparatus of claim 208 wherein said hole is slightly offset from the center of said platter.
- 211. (Previously Presented) The apparatus of claim 208 wherein said platter holds said megasonics transducers substantially parallel to the backside of said wafer.
- 212. (Previously Presented) The apparatus of claim 208 wherein said megasonics transducers cover at least 80% of said wafer backside.
- 213. (Previously Presented) The apparatus of claim 203 wherein said platter has a diameter greater than the diameter of said wafer.
- 214. (Previously Presented) An apparatus for wet processing a device side of an individual wafer comprising:
 - a platter having a plurality of megasonics transducers;

Application No.: 09/891,849

Filing Date: June 25, 2001

- 8/23**-**

a wafer holder to position a wafer having a device side and a non-device side above said platter such that said wafer non-device side is separated by gap from said platter; and

a nozzle to provide a cleaning fluid onto said wafer device side.

- 215. (Previously Presented) The apparatus of claim 214 further comprising an opening in said platter to flow a fluid in said gap between said wafer non-device side and said platter.
- 216. (Previously Presented) The apparatus of claim 214 wherein said megasonics transducers are formed on said platter backside.
- 217. (Previously Presented) The apparatus of claim 214 wherein said platter holds said megasonics transducers substantially parallel to the said wafer non-device side.
- 218. (Previously Presented) The apparatus of claim 214 wherein said megasonics transducers cover at least 80% of said wafer non-device side.
- 219. (Previously Presented) An apparatus for wet processing a frontside of an individual wafer comprising:

a wafer holder to position a wafer having a frontside and backside above a platter having a frontside and backside such that said wafer backside is separated by a gap from said platter frontside;

a plurality of megasonics transducers formed on said platter backside wherein said megasonics transducers covers at least 80% of said wafer backside and wherein said platter positions said megasonics transducers substantially parallel to

Application No.: 09/891,849

Filing Date: June 25, 2001

- 9/23-

the backside of said wafer and wherein said platter has a diameter greater than the diameter of said wafer;

an opening in said platter to flow fluid in said gap between said wafer backside and said platter frontside; and

a nozzle positioned above said wafer frontside for directing a cleaning fluid onto said wafer frontside.

220. (Previously Presented) The apparatus of claim 219 wherein said megasonics transducers provide full coverage of said wafer backside.

221. (New) The apparatus for wet processing individual wafers of claim 1, wherein the acoustic energy generator comprises a plurality of acoustic wave transducers having different resonance frequencies.

222. (New) The apparatus for wet processing individual wafers of claim 221, wherein the plurality of acoustic wave transducers having different resonance frequencies are selected to effectively remove different sized particles from the device side of the wafer.

223. (New) The apparatus for wet processing individual wafers of claim 221, wherein the different resonance frequencies comprise about 900 KHz and about 1.8 MHz.

Application No.: 09/891,849 Filing Date: June 25, 2001

- 10/23-

- 224. (New) The apparatus for wet processing individual wafers of claim 1, wherein the acoustic energy generator comprises an acoustic wave transducer having a resonance frequency, which minimizes sonic wave reflections in the wafer.
- 225. (New) The apparatus for wet processing individual wafers of claim 1, wherein the first liquid and the process liquid are different liquids while they are in contact with the non-device side and device side of the wafer, respectively.
- 226. (New) The apparatus for wet processing individual wafers of claim 1, wherein the process liquid is limited to a relatively thin layer of process liquid on the device side of the wafer, so as to concentrate the sonic energy within the thin liquid layer to facilitate the removal of particles without substantially increasing the risk of damage to the devices on the wafer.
- 227. (New) The apparatus for wet processing individual wafers of claim 1, wherein the acoustic energy generator comprises a plurality of acoustic wave transducers having different resonance frequencies, in which their intensities are separately controllable.
- 228. (New) The apparatus for wet processing individual wafers of claim 45, wherein the plurality of transducer cover greater than 80% of the platter backside area.
- 229. (New) The apparatus for wet processing individual wafers of claim 45, wherein the platter further comprises a coating on the platter frontside.

Application No.: 09/891,849

Filing Date: June 25, 2001

- 11/23-

AMAT Ref. No.: 004711USAPY1/W-C/W-C/

BSTZ Ref. No.: 004887.P454X

- 230. (New) The apparatus for wet processing individual wafers of claim 45, wherein the platter has a diameter greater than the wafer to be processed.
- 231. (New) The apparatus for wet processing individual wafers of claim 45, wherein the wafer bracket positions the wafer substantially centered over the platter.
- 232. (New) The apparatus for wet processing individual wafers of claim 45, wherein the plurality of megasonic transducers comprise a plurality of piezoelectric transducers having different resonance frequencies.
- 233. (New) The apparatus for wet processing individual wafers of claim 232, wherein the plurality of piezoelectric transducers having different resonance frequencies are selected to effectively remove different sized particles from the device side of the wafer.
- 234. (New) The apparatus for wet processing individual wafers of claim 233, wherein the different resonance frequencies comprise about 900 KHz and about 1.8 MHz.
- 235. (New) The apparatus for wet processing individual wafers of claim 45, wherein the plurality of megasonic transducers comprises a piezoelectric transducer having a resonance frequency, which minimizes megasonic reflections in the wafer.
- 236. (New) The apparatus for wet processing individual wafers of claim 45, wherein the said liquid and the said process liquid are different fluids, which are

Application No.: 09/891,849

Filing Date: June 25, 2001

- 12/23-

maintained separate from each other before and while in contact with the nondevice side and device side of the wafer, respectively.

237. (New) The apparatus for wet processing individual wafers of claim 45, wherein the process liquid is limited to a relatively thin layer of process liquid on the device side of the wafer, so as to concentrate the sonic energy within the thin liquid layer to facilitate the removal of particles without substantially increasing the risk of damage to the devices on the wafer.

238. (New) The apparatus for wet processing individual wafers of claim 45, wherein the plurality of megasonic transducers comprise a plurality of piezoelectric transducers having different resonance frequencies, in which their intensities are separately controllable.

239. (New) The apparatus for wet processing individual wafers of claim 45, wherein the platter further comprises an opening in said platter to flow a fluid in said gap between said wafer backside and said platter frontside.

(New) The apparatus of claim 239 wherein said hole is positioned 240. substantially in the center of said platter.

(New) The apparatus of claim 239 wherein said hole is slightly offset from the center of said platter.

Application No.: 09/891,849 Filing Date: June 25, 2001

AMAT Ref. No.: 004711USAPY1/W-C/W-C/ BSTZ Ref. No.: 004887 P454X